

# SY6410 Quick Start Guide

## 1. Overview

SY6410 is a simple gas gauge IC for single cell lithium-ion (Li+) batteries in handheld and portable equipment. SY6410 senses battery terminal voltage and use the proprietary algorithm to calculate the corresponding State of Charge (SOC). Comparing with conventional voltage-based gauge which translates terminal voltage directly to SOC, the advanced algorithm in SY6410 shows great advantage in SOC accuracy. SY6410 can be classified as advanced voltage-based gauge without current sensor and the SOC accuracy will not degrade with time. Temperature of the battery pack is measured by the host microcontroller and feed to SY6410 through the I2C interface. SY6410 can automatically compensate temperature, load variation and battery age.

### 2. Hardware

SY6410 is available in DFN2×2-8 package. The chip has 8 pins, the top view is shown in Figure 1:





The application circuit of SY6410 is shown in Figure 2:



**Figure 2 Basic Architecture Information** 

The functions of the pins are as table1:

Table 1 The functions of the pins

Pin Name	Description
CTG	Connect to GND.
CELL	Battery voltage monitors I/O. Bypass with a $1\mu$ F capacitor to the GND. Connect to battery's positive terminal through R5
VDD	Power supply input. Bypass with a $1\mu$ F capacitor to GND. Connect to battery's positive terminal through R4
GND	Ground. Connect to battery's negative terminal.
ALRT	Open-drain output. Low SOC alarm signal. When SOC is below the threshold, this pin will be pulled down.
NC	No connection. NC is recommended to connect to GND.
SCL	I2C clock input. SCL has an internal pull-down resistance.
SDA	I2C data input/output. SDA has an internal pull-down resistance.

The steps to connect the hardware are as follows:

a. The top view of SY6410 demo board is shown in Figure 3:



Figure 3 SY6410 Demo Board Top View

b. Typically, the SY6410 is always battery powered, even when the system is down. When power up SY6410,



the power supply must meet the following requirements: VDD=4 to 5.5V and no working current.

c. Connect the corresponding ports of I2C and SY6410 demo (VCC, GND, SDA, SCL).

## **3. GUI**

After Battery learning is completed (refer to section 4 (1) for details on battery learning), the gauge configuration file will be sent to customer using following folder structure: (1) Battery test report and memory burn instructions;(2) Silergy I2C Burn Tool. As shown in Figure 4:

D:\Battery test report and burn instructions						
名称 ^	修改日期	类型				
Battery test report and memory burn instructions	2023/3/13 16:02	文件夹				
늘 Silergy I2C Burn Tool	2023/3/13 10:47	文件夹				

Figure 4 Folder description

### (1) Configuration File Structure

Battery test report and memory (MTP) program instructions contain three types of files. Battery Memory Data(word/pdf) file records MTP data, and Battery Test Report (word/pdf) file records test cases and test results. The Process of Writing and Reading the MTP of SY6410 file records the steps of writing and reading the MTP of SY6410.

In the Silergy I2C Burn Tool folder, CH341PAR (.exe) is the I2C driver, SY6410 (.exe) is the operating interface of the SY6410 chip, and Tab is the MTP Data.

#### (2) Install Software

- a. To install the I2C driver, double-click CH341PAR.exe in path "...\Battery test report and burn instructions\Silergy I2C Burn Tool". Click Install.
- b. After connecting I2C, double-click SY6410.exe in path "...\Battery test report and burn instructions\Silergy I2C Burn Tool" to open the SY6410 operation interface.

### 4. Configure SY6410

#### (1) Generate the Battery Model

The battery model is obtained through the actual test of the target battery. The items to be tested are: charge curve, discharge curve and discharge OCV curve. It should be noted that the test item must be a complete charge and discharge process, including current, voltage, relax process, time stamp that captured every two seconds. In addition, when temperature compensation is required, it is also necessary to test the charge and discharge curve at multiple temperatures.



A set of MTP parameters will be generated by modeling the data captured, including SOC-OCV table, charge and discharge parameters, temperature compensation parameters and other information. Specific information is shown in Table 2:

Table 2 MTP parameters					
ADDRESS	DESCRIPTION				
7'h00-7'h12	19 SOC values				
7'h13-7'h17	5 NTC voltage values				
7'h18-7'h1C	5 null values				
7'h1D-7'h2F	19 charging information values				
7'h30-7'h44	21 discharging information values				
7'h45-7'h70	44 OCV values				
7'h71-7'h77	7 trim values				
7'h78-7'h7F	8 temperature information values				

#### (2) Load the Battery Model

a. Click **MTP Function** to write MTP parameters. As shown in Figure 5:



#### **Figure 5 Open MTP Function**

b. When writing MTP parameter, first check whether the address is 0x30 and then perform four steps: (1) **Read form File**; (2) **Write Tab**; (3) **Read Tab**; (4) **Check**. Note When writing MTP data, do not have working current. The steps for writing MTP parameters are shown in Figure 6:





Figure 6 Steps for writing MTP

#### (3) Set up the Register

After writing MTP parameters, you need to exit sleep mode if you want SY6410 to work properly.

Click **I2C Debugger** in the lower right corner of the SY6410 operation interface to enter the General Debugger interface.

First click Scan and the address is 30; then click REGISTER MODE. As shown in Figure 7:

🧼 CH341 I2C General Del	ougger Rev 4.0 2018030	19		- 🗆 X
USB-I2C Port Bit Rate Driver 1 V 20kHz	Transmission Mod		Address_7bic(hex)	
Write Data(hex)	Load	Sie Sie	p i	
00			Vrite Length(byte)	
Read Data(hex)	Save	Date		I2C Stream (Random Read)
List of ack slave addre:	ss(7bit): <0x30>	^	Read Length(byte) 2 * I2C Read	
	step 2	-	,	
GPIO CONTROL	REGISTER MODE	PART MODE	PART MODE MULTI ADDR	EEPROM MODE

#### Figure 7 REGISTER MODE

Enter the **REGISTER MODE** screen, and write the address of 0x06 to 20 and the address of 0x0d to 9C. The

operation to write the address of 0x0d is the same as that of 0x06.

The operation is as follows: (1) Click Scan and the address is 30; (2) Input 6 in Register Address\_start ; (3) Input

20 in Register Data ; (4) Click Write Register; (5) Input 6 in Register Address\_start; (6) Click Read Register;

(7) check. The operation method of entering and exiting Sleep Mode is shown in Figure 8:

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CH341 I2C Debugger-Register Mode Rev 4.0 20	180309	-		×
Register Address Size	I2C Slave Address_/bit() 30 5 step 1	nex) Scan		
step 2 Register Data(hex)				
Register Address Start(hex) 6 : step 3	step 4	Length Writ	n(byte) 1 :e Regis	ster
Read Register Operation				
Register Address 20 Start(hex) 6 ÷ step 5	step 6	Lengtl	n(byte) 1 d Regis	• ter
			_	
LIST OF BOX SLEVE BOOFESS(/bit): (UX3U)				

**Figure8 Operation Method of Sleep Mode** 

Because the SY6410 does not sample the temperature, it needs to be written externally. TEMP is the value of battery's temperature, which can be written by I2C interface. The address of the TEMP register is 0x0C. The 0x0C address information is shown in Figure 9:

MSB —ADDRESS 0x0C							
х	х	х	TEMP4	TEMP3	TEMP2	TEMP1	TEMP0
Msb							Lsb



The default value of TEMP is  $0x3C(20^{\circ}C)$ . The following formula is the calculation of TEMP.

 $TEMP = DEC2HEX(INT(temperature(^{\circ}C) + 40))$ 

#### (4) Data Monitoring and Preservation

Monitor battery VBAT and SOC data. First click **Setting Monitor** and then Click **Start** to display the VBAT and SOC data. During this process, the chip is working properly and the battery can have working current. Operation is shown in Figure 10:





ting and Monitor	MTP Functi	on							S
SLEEP	WARE	ALT C	Lo	op Read Delay 1	000 🔹 ns Lo	gging 🗆 🛛 S	top		SILERG
Low SOC Alart	4.00 ♀ % 3.000 ♀ γ		Read Value	VBAT	3. 7128 🔹 y	SOC 7.06	<u>*</u> %	DevAddr_71 0x30	×it ∽
5.007							_		
4. 757							_		
4.500						1	_		
4. 257							_		
4.007									
3. 757	L	_		_		_	~		
3. 507							_		
3.257							_		
3.000							_		
2.757							-		
2 500							_		

Figure 10 Monitor VBAT and SOC Data

If you want to save the data read by the SY6410, please check Logging and then click Start, Logging will produce a

text document containing Time, Voltage, SOC and other information. As shown in Figure 11:

SY6410 Evalutions Ki	t Rev 1.0 20180309				- ×
etting and Monitor	MIP Function				5
SLEEP	WARE ALT CLR	Loop Head Delay 1000	🔹 ms Logging 🗹	START	SILERGY
Low SOC Alart 4	00 🚔 % - Bei	d Value			Dowaddw 7hi+
Reset Voltage 3.	000 ‡ v	ALT VBAT 0.	0000 🛊 y soc 0.	00 😩 %	0x30 ~
VBAT SOC					
5.007					
4.757					
4. 509					
4.007					
3. 757					
3.50V					
3.007					
2.757					
2.50V		Samplar		4096	
					I2C Debugger
ate	Time	Alart	Voltage(	V)	SOC(%
3/06/09	08:47:32	FALSE	4.3127	98.13	3
3/06/09	08:47:33	FALSE	4.3134	98.13	3
3/06/09	08:47:34	FALSE	4.3127	98.13	3
3/06/09	08:47:35	FALSE	4.3134	98.13	3
3/06/09	08:47:36	FALSE	4.3127	98.13	3
3/06/09	08:47:37	FALSE	4.3127	98.13	3
3/06/09	08:47:38	FALSE	4.3127	98.13	3
3/06/09	08:47:39	FALSE	4.3127	98.13	3
3/06/09	08:47:40	FALSE	4.3134	98.13	3
3/06/09	08:47:41	FALSE	4.3134	98.13	3
3/06/09	08:47:42	FALSE	4.3127	98.13	3
2 100 100	00.47.42	EALCE	A 212A	00.11	<b>b</b>
	Figi	ire 11 Los	gging Date		

### 5. Tips

a. When reading or writing MTP data, ensure that power supply is not providing power for other use (such as

charging or discharging batteries) to ensure supply voltage and current are stable.

b. The SY6410 chip is powered off. When reconnecting the power supply, ensure that the power supply has no

working current.

c. When entering and exiting the Sleep Mode, ensure that the power supply has no working current.